

Data sheet acquired from Harris Semiconductor SCHS038C – Revised October 2003

CMOS 4-Stage Parallel In/Parallel Out Shift Register

with J-K Serial Inputs and True/Complement Outputs

High-Voltage Types (20-Volt Rating)

■ CD4035B is a four-stage clocked signal serial register with provision for synchronous PARALLEL inputs to each stage and SERIAL inputs to the first stage via JK logic. Register stages 2, 3, and 4 are coupled in a serial D flip-flop configuration when the register is in the serial mode (PARALLEL/SERIAL control low).

Parallel entry into each register stage is permitted when the PARALLEL/SERIAL control is high.

In the parallel or serial mode information is transferred on positive clock transitions.

When the TRUE/COMPLEMENT control is high, the true contents of the register are available at the output terminals. When the TRUE/COMPLEMENT control is low, the outputs are the complements of the data in the register. The TRUE/COMPLEMENT control functions asynchronously with respect to the CLOCK-signal.

JK input logic is provided on the first stage SERIAL input to minimize logic requirements particularly in counting and sequence-generation applications. With JK inputs connected together, the first stage becomes a D flip-flop. An asynchronous common RESET is also provided.

The CD4035B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

- 4-Stage clocked shift operation
- Synchronous parallel entry on all 4 stages
- JK inputs on first stage
- Asynchronous True/Complement control on all outputs
- Static flip-flop operation; Master-slave configuration
- Buffered inputs and outputs
- High speed 12 MHz (typ.) at V_{DD} = 10 V
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of "B" Series CMOS Devices"

Applications:

- Counters, Registers
 Arithmetic-unit registers
 Shift-left shift right registers
 Serial-to-parallel/parallel-to-serial conversions
- Sequence generation
- Control circuits
- Code conversion

FIRST STAGE TRUTH TABLE

	†n-	(INP	JTS }		tn (OUTPUTS)
CL	J	K	R	Q _{n-1}	Qn
	0	х	0	0	0
	1	х	0	0	ı
	х	0	0	ı	0
	1	0	0	Q _{n-1}	Q _{n-1} TOGGLE MODE
	х	-	0	1	ı
	x	x	0	Q _{n-1}	Q _{n-I}
×	х	х	ı	×	0

PARALLEL IN 9 1 10 2 11 3 12 4 SER. 5 4 CLK 6 P/S 7 T/C 2 RESET 5 VOD *16 VSS *8 Q1/Q1 Q2/Q2 Q3/Q3 Q4/Q4 T/C' OUT 92C9 - 29054R1 FUNCTIONAL DIAGRAM

CD4035B Types

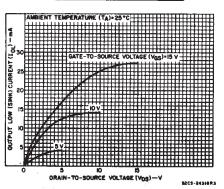


Fig. 1 — Typical output low (sink) current characteristics.

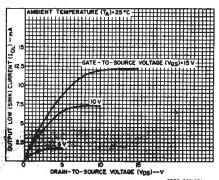
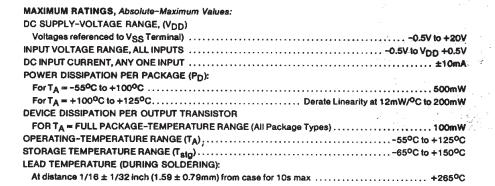


Fig. 2 - Minimum output low (sink)

current characteristics.

Fig. 3 — Typical output high (source) current characteristics.



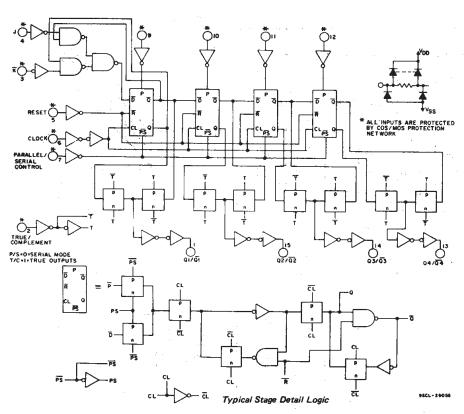


Fig. 4 - Logic diagram.

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}$ C, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V_{DD}	LII	MITS	UNITS
	 (V)	MIN.	MAX.	
Supply-Voltage Range (For T _A = Full Package-Temperature Range)		3	18	V
Data Setup Time, t _S : J/K Lines	5 10 15	220 80 60	- -	ns
Parallel-In Lines	5 10 15	140 50 40	-	ns
Clock Pulse Width, t _W	5 10 15	200 90 60	_ 	ns
Clock Input Frequency, fCL	5 10 15	dc	2 6 8	MHz
Clock Rise or Fall Time, t _r CL, t _f CL:	5 10 15		15 15 15	μs
Reset Pulse Width, t _W	5 10 15	250 110 80		ns

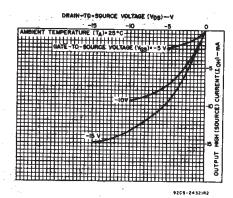


Fig. 5 — Minimum output high (source) current characteristics.

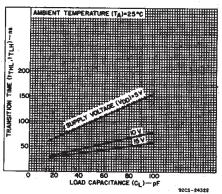


Fig. 6 — Typical transition time as a function of load capacitance.

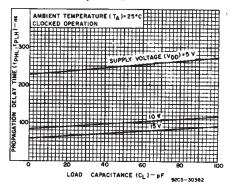


Fig. 7 — Typical propagation delay times as a function of load capacitance (Q output).

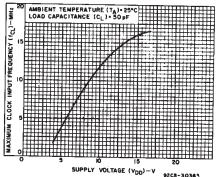


Fig. 8 — Typical maximum clock input frequency as a function of supply voltage.

CD4035B Types

CHARAC- TERISTIC	CON	DITIO	NS	Lim	IITS AT I	NDICAT	ED TEMI	PERATI	JRES (°C	C)	UNIT
	v _o	VIN	v_{DD}					+25			s
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent	_	0,5	5	5	5	150	150	_	0.04	5	
Device		0,10	10	10	10	300	300	-	0.04	10	μА
Current, IDD Max.	'	0,15	15	20	20	600	600	_	0.04	20	[
DD Max		0,20	20	100	100	3000	3000	-	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	m/
(Source)	2.5	0,5	5	-2	1.8°	-1.3	-1.15	-1.6	- 3.2	-	
Current, IOH Min.	9.5	0,10	10	1.6	-1.5	-1.1	-0.9	1.3	-2.6	-]
	13.5	0,15	15	-4.2	-4	-2.8	- 2.4	-3.4	-6.8	_	
Output Voltage:	-	0,5	5		0.	.05	_	0	0.05		
Low-Level,	3.1	0,10	10		0	.05			0	0.05	
VOL Max.		0,15	15		0.	05			0	0.05	V
Output		0,5	- 5		4.	95		4.95	5		
Voltage: High-Level,		0,10	10		9	95		9.95	10	.,-	
VOH Min.		0,15	15		14.	95		14.95	15		
leavet Law	0.5,4.5		5			1.5		-	-	1.5	
Input Low Voltage	1,9		10			3			-	3	
V _{IL} Max.	1.5,13.5		15			4			-	4	v
Input High	0.5,4.5		5			3.5		3.5	-	_	
Voltage,	1,9	-	10			7		7	-	_	
V _{IH} Min.	1,5,13.5	- "	15		,	11		11			L
Input Current I _{IN} Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10-5	±0.1	μΔ

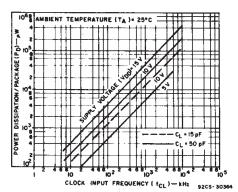


Fig. 9 — Typical dynamic power dissipation as a function of clock input frequency.

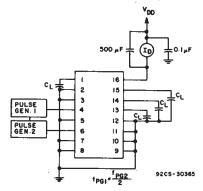


Fig. 10 - Dynamic power dissipation test circuit.

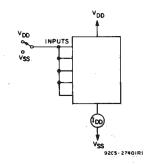


Fig. 11 - Quiescent-device current test circuit.

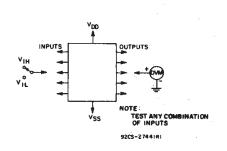


Fig. 12 - Input-voltage test circuit.

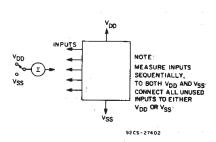


Fig. 13 - Input-current test circuit.

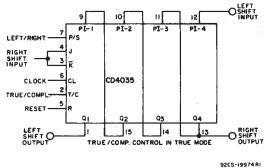
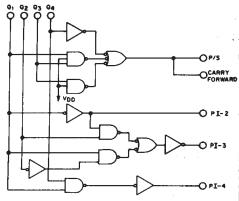


Fig. 14 — Shift left/shift right register.

CD4035B Types



Using Couleur's Technique (BIDEC)^A, a binary number (most significant bit, MSB) first is shifted and processed, such that the BCD equivalent is obtained when the last binary bit is clocked into the register. The CD4035B, with the correct conversion logic, can also be used as a BCD-to-binary converter.

Fig. 15 - BIDEC logic.

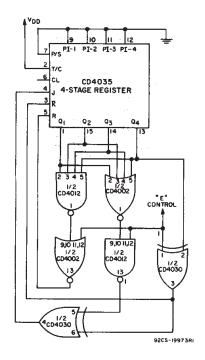


Fig. 16(a) — Double sequence generator.

DYNAMIC ELECTRICAL CHARACTERISTICS

At $T_A = 25^{\circ}C$, Input t_f , $t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200$ k Ω

CHARACTERISTICS		TEST DITIONS		LIMITS			
CHARACTERISTICS		V _{DD} (V)	Min.	Тур.	Max.	UNITS	
CLOCKED OPERATION							
Propagation Delay Time:		5		250	500		
tPHL, tPLH		10	-	100	200	ns	
		15	-	75	150	Į	
Tonnisian Times		5		100	200		
Transition Time: tTHL, tTLH		10	_	50	100	ns	
THE TEN		15	<u> </u>	40	80		
		5		100	200		
Minimum Clock Pulse Width, t _W		10		45	90	ns	
		15	-	30	60		
Clock Rise or Fall Time, t _f CL, t _f CL*	7	5,10, 15	_	_	15	μs	
		5	_	110	220		
Minimum Setup Time: J/K Lines		10	[40	80	ns	
J/K Lines		15	_	30	60		
		5	_	70	140		
Parallel-In-Lines		10	_	25	50	ns	
		15	-	20	40		
		. 5	2	4	-, 1, 5		
Maximum Clock Frequency, f _{CL}		10	6	12	_ *	MHz	
		15	8	16	_		
Input Capacitance, CIN	Any	Input	-	5	7.5	pF	
RESET OPERATION							
Propagation Delay Time:		5	_	230	460		
tphL, tpLH		10	_	100	200	ns	
		15	-	80	160		
	1	5	_	125	250		
Minimum Reset Pulse Width, tw		10	, – ·	55	110	ns	
<u> </u>		15		40	40		

^{*}If more than one unit is cascaded t.CL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.

ontrol	E =	O			1		1		
	01	0.2	Q3.	04		0,	02	03	04
	Ä	8	C	. D		, A	В	С	D
	0	0	0	0	15	1	- 11	. 1911	1
1	1 1	0	0	0	114	Õ	1	1.1	1
2	2 0	1	0	0	13	1	0	1	1
Ę	5 1	0	1	0	10	0	1	0	1 .
10	0 (1	0	1	5	1	0	1	0
. 4	0	0	1	0	11	1	1	Ó	1
٤) 1	0	0	1	6	0	1	1	Ó
3	3 1	1	0	0	12	O	0	1	1
6	. 0	1	1	0	9	1	0	0	1
13	3 1	0	1	1	2	0	1	ō	Ó
11	1	1	0	1	4	ō	Ó	ī	ŏ
7	1	1	1	0	8	0	O	Ó	1
14	0	1	1	1	1	1	ō	ă	ò
12	2 0	0	1	1	3	1	1	ō	ō
8	0	0	0	1	1 7	1	1	1	ŏ

Using a control line (E) two different state sequences can be generated. For example, suppose the following two sequences are desired on command (control line E)

Fig. 16(b) — State sequences.

[♠] The basic rule is: If a 4 or less is in a decade, shift with the next clock pulse; if a 5 or greater is in a decade, add 3 and then shift at the next clock pulse. For more information refer to "IRE TRANSACTIONS ON ELECTRONIC COMPUTERS", Dec. 1958, Pages 313—316.

CD4035B Types

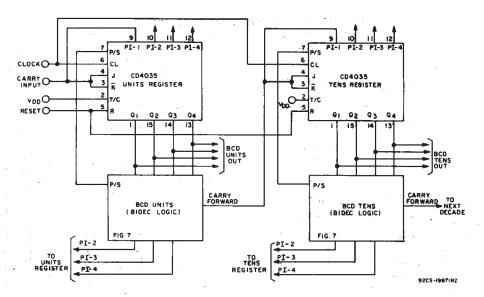
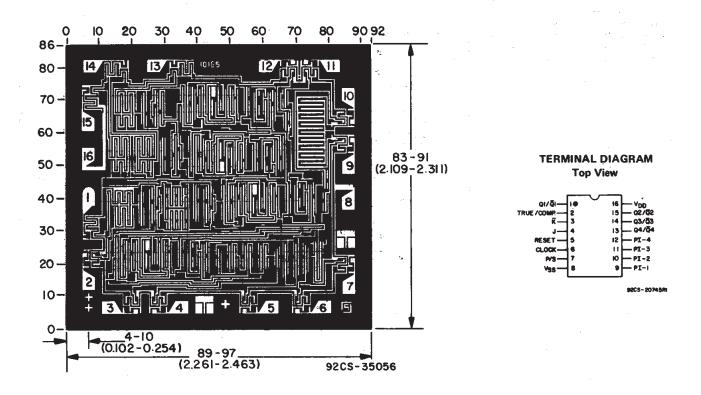


Fig. 17 - Binary-to-BCD converter.



Dimensions and pad layout for CD4035BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3}) inch).





18-Feb-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
8101701EA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8101701EA CD4035BF3A	Samples
CD4035BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4035BE	Samples
CD4035BF	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4035BF	Samples
CD4035BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8101701EA CD4035BF3A	Samples
CD4035BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4035BM	Samples
CD4035BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4035BM	Samples
CD4035BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM035B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4035B, CD4035B-MIL:

Catalog: CD4035B

Military: CD4035B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

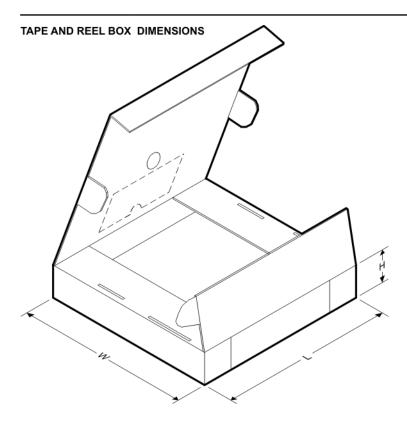
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4035BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4035BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4035BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4035BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4035BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4035BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4035BM	D	SOIC	16	40	507	8	3940	4.32

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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